

# Device Modeling Report

COMPONENTS:  
DIODE/ GENERAL PURPOSE RECTIFIER / PROFESSIONAL  
PART NUMBER: RHRP30120  
MANUFACTURER: INTERSIL  
REMARK: TC=150C

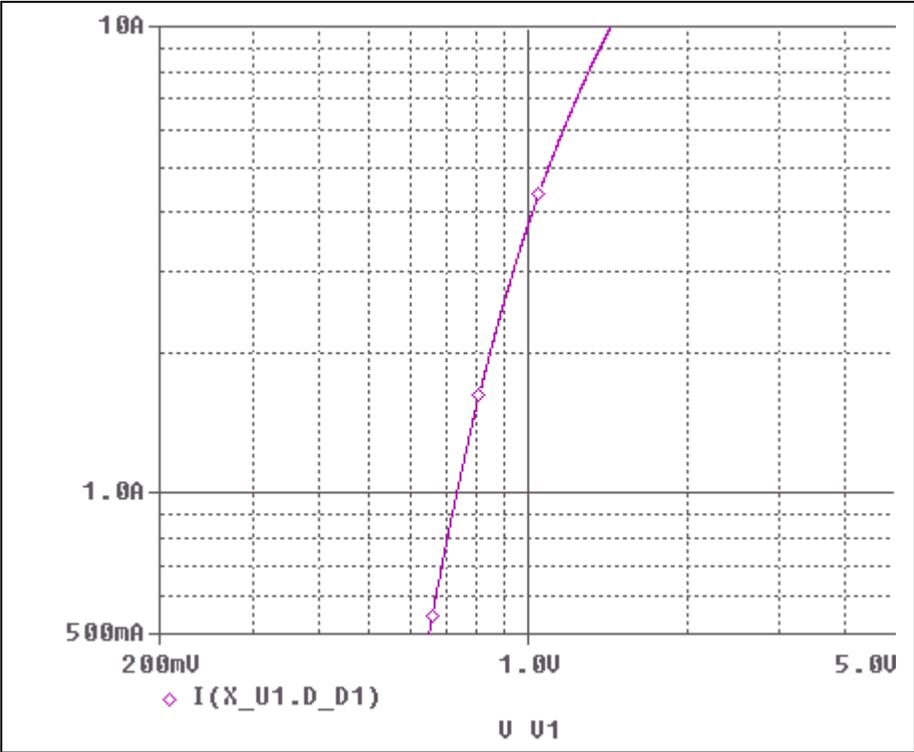


**Bee Technologies Inc.**

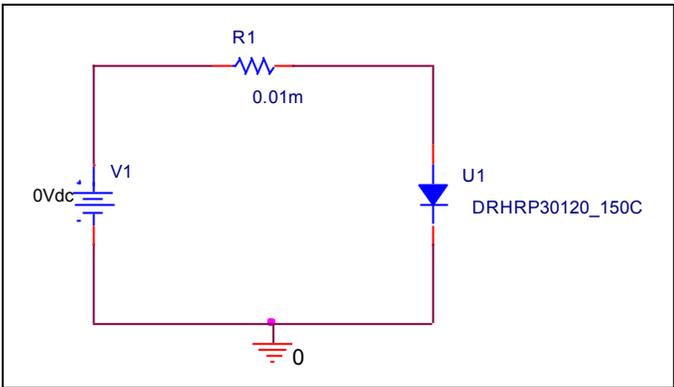
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

# Forward Current Characteristic

## Circuit Simulation Result

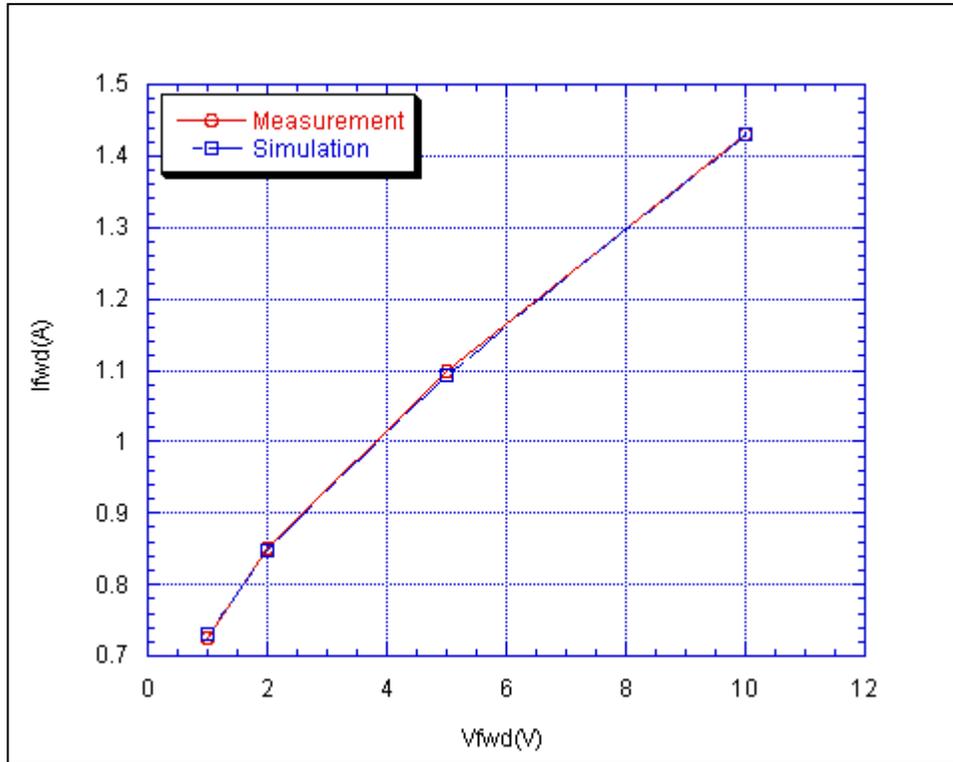


## Evaluation Circuit



# Comparison Graph

## Circuit Simulation Result

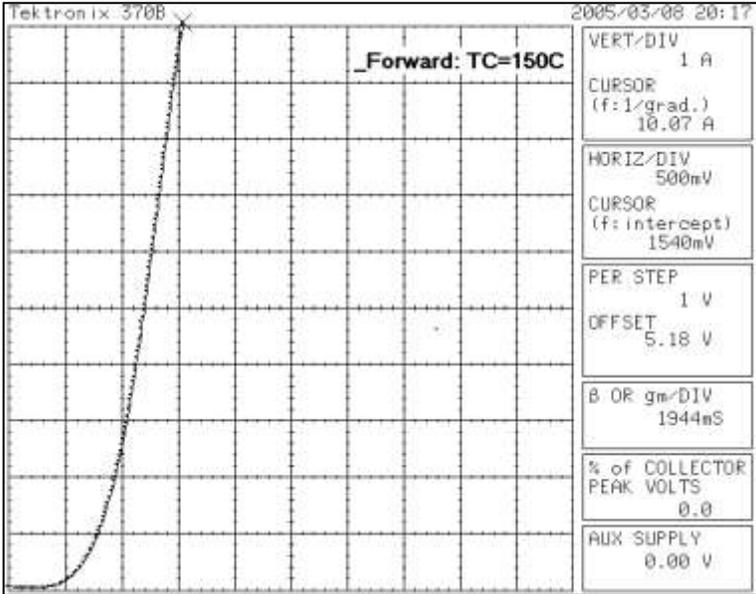


## Simulation Result

Ifwd(A)	Vfwd(V) Measurement	Vfwd(V) Simulation	%Error
1	0.725	0.732	-0.97
2	0.850	0.847	0.35
5	1.100	1.093	0.64
10	1.430	1.430	0.00

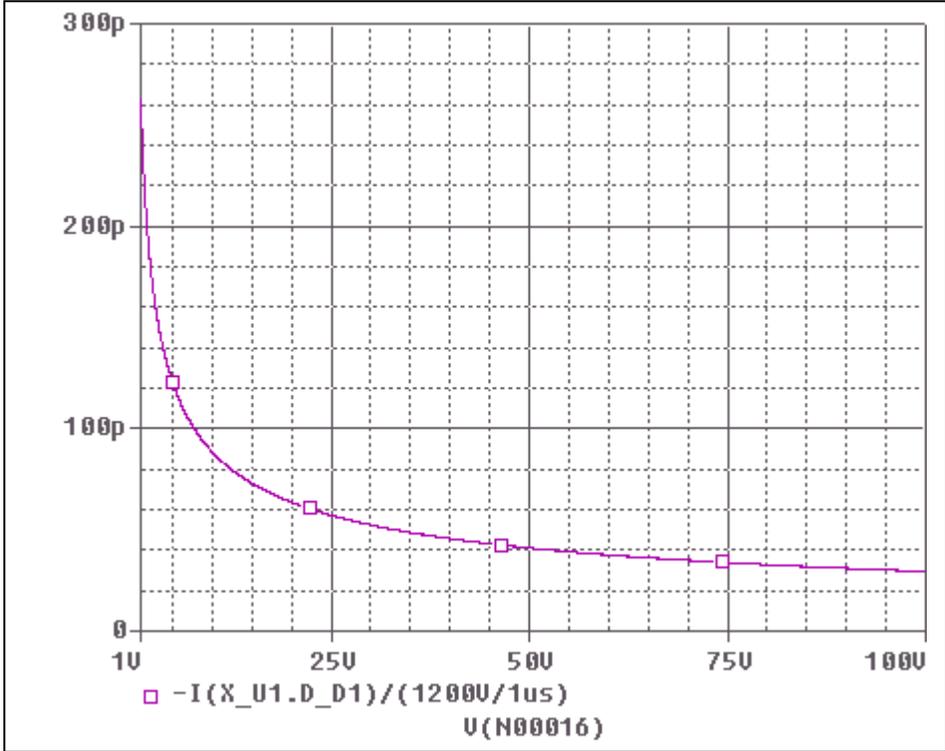
# Forward Current Characteristic

# Reference

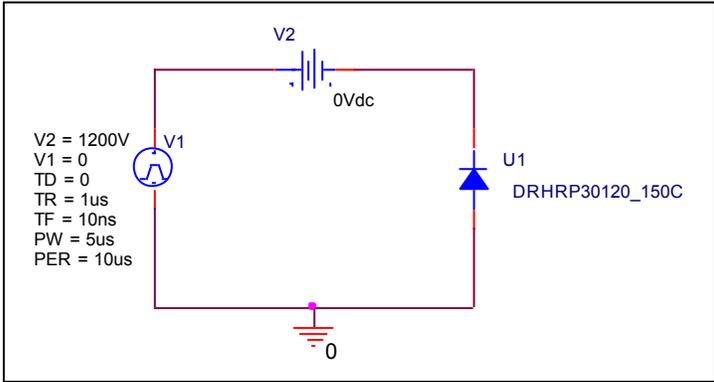


# Capacitance Characteristic

## Circuit Simulation Result

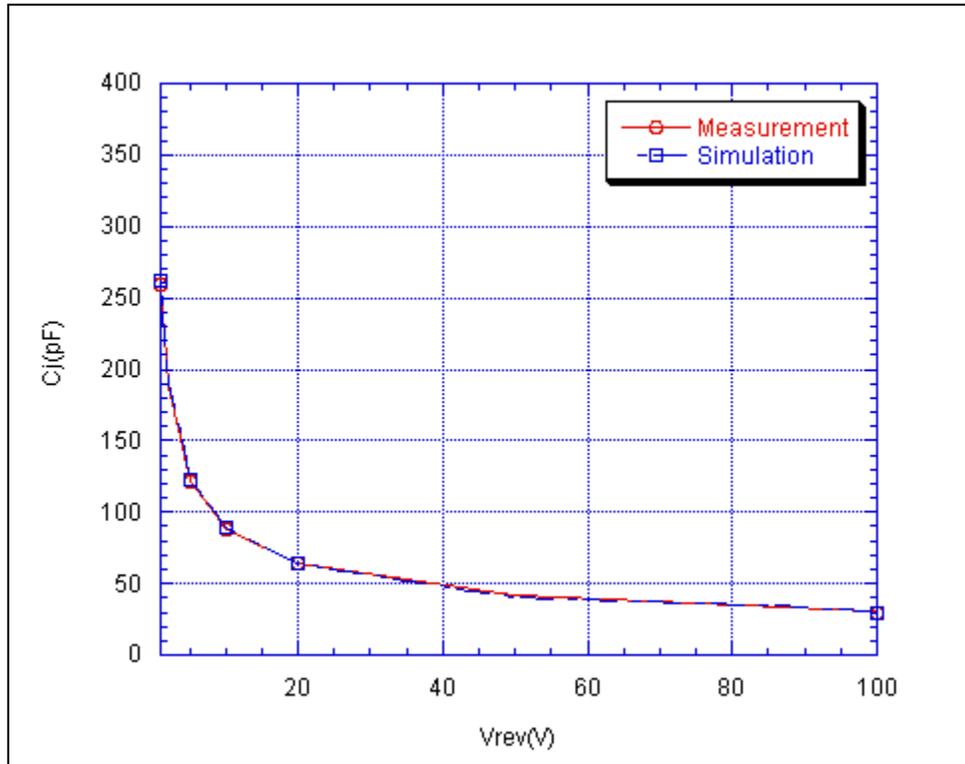


## Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result

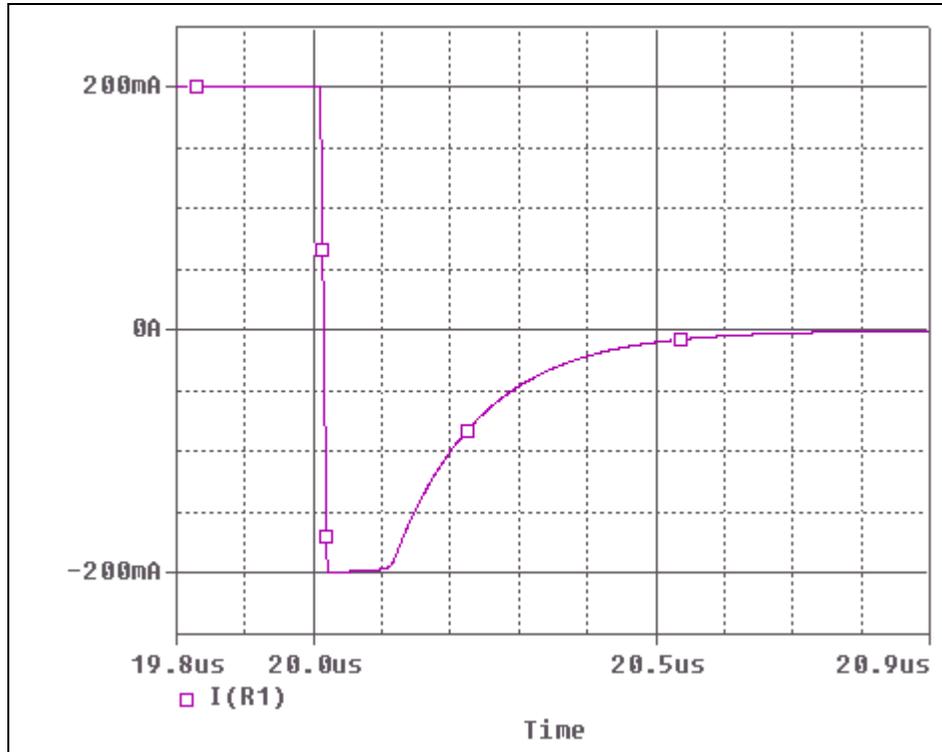


### Simulation Result

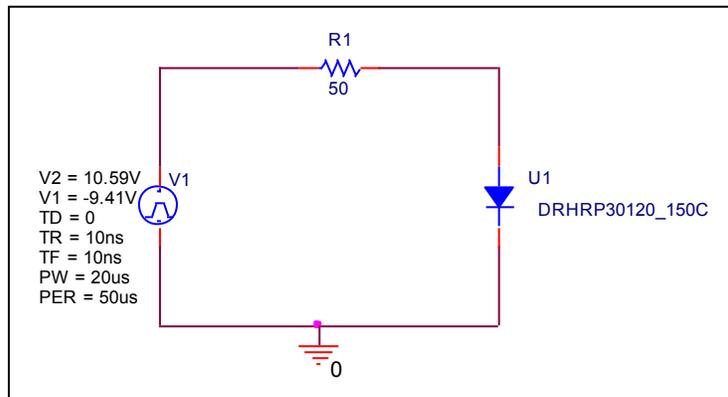
Vrev(V)	Cj(pF) Measurement	Cj(pF) Simulation	%Error
0	571.000	571.000	0.00
1	259.000	262.245	-1.25
2	188.000	189.633	-0.87
5	122.000	123.176	-0.96
10	88.000	88.609	-0.69
20	64.000	63.585	0.65
50	42.000	41.011	2.35
100	30.000	29.409	1.97

# Reverse Recovery Characteristic

## Circuit Simulation Result



## Evaluation Circuit

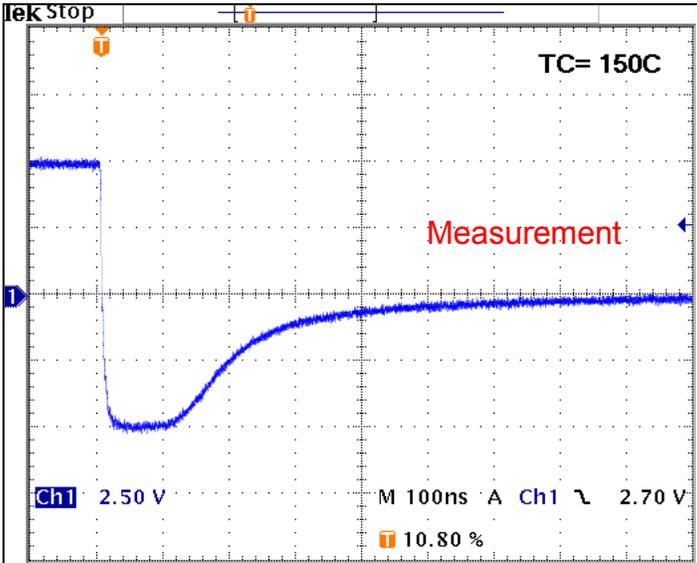


## Compare Measurement vs. Simulation

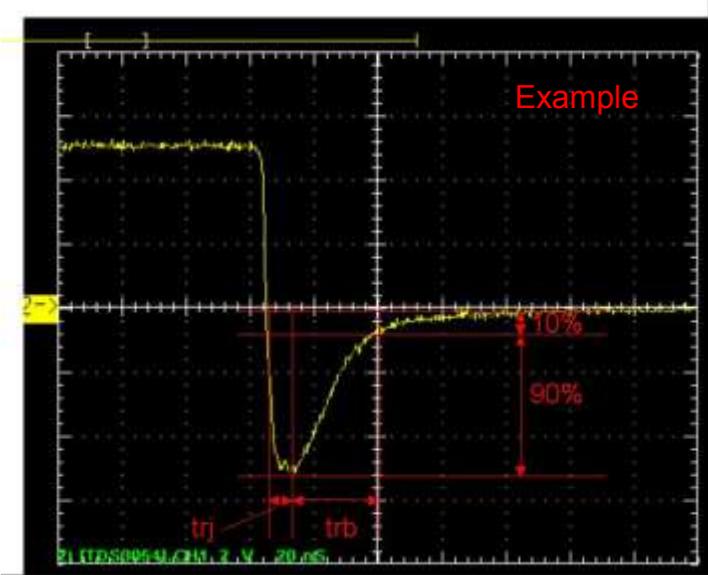
	Measurement		Simulation		%Error
trj	96.00	ns	96.21	ns	0.218
trb	296.00	ns	296.14	ns	0.047

# Reverse Recovery Characteristic

# Reference



Trj =96 (ns)  
Trb=296 (ns)  
Conditions: Ifwd=Irev=0.2(A), RI=50



Relation between trj and trb